THE DATASHEET OF

NCP152MX300280TCG

www.win-source.net 0086-755-83957316

Voltage Regulator - Dual, Low I_Q, Low Dropout

150 mA

NCP152

The NCP152 is 150 mA, Dual Output Linear Voltage Regulator that provides a very stable and accurate voltage with very low noise and high Power Supply Rejection Ratio (PSRR) suitable for RF applications. The device doesn't require any additional noise bypass capacitor to achieve very low noise performance. In order to optimize performance for battery operated portable applications, the NCP152 employs the Adaptive Ground Current Feature for low ground current consumption during light−load conditions.

Features

- Operating Input Voltage Range: 1.9 V to 5.25 V
- Two Independent Output Voltages:
  (for details please refer to the Ordering Information section)
- Very Low Dropout: 150 mV Typical at 150 mA
- Low IQ of typ. 50 μA per Channel
- High PSRR: 75 dB at 1 kHz
- Two Independent Enable Pins
- Thermal Shutdown and Current Limit Protections
- Stable with a 0.22 μF Ceramic Output Capacitor−
- Available in XDFN6 1.2 x 1.2 mm Package
- Active Output Discharge for Fast Output Turn−Off
- These are Pb−Free Devices

Typical Applications

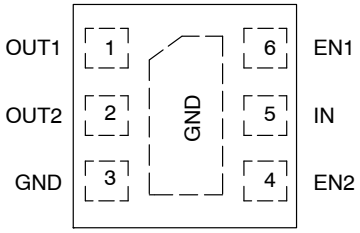
- Smartphones, Tablets, Wireless Handsets
- Wireless LAN, Bluetooth®, ZigBee® Interfaces
- Other Battery Powered Applications

XDFN6, 1.2x1.2
CASE 711AT

MARKING DIAGRAM

XX = Specific Device Code
M = Date Code

PIN CONNECTIONS



XDFN6
(Top view)

ORDERING INFORMATION

See detailed ordering and shipping information on page 17 of this data sheet.

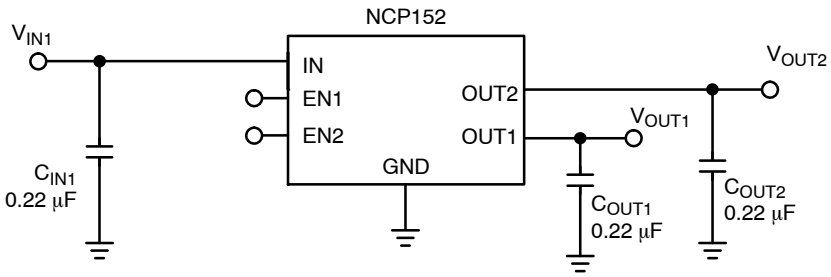


Figure 1. Typical Application Schematic

© Semiconductor Components Industries, LLC, 2016

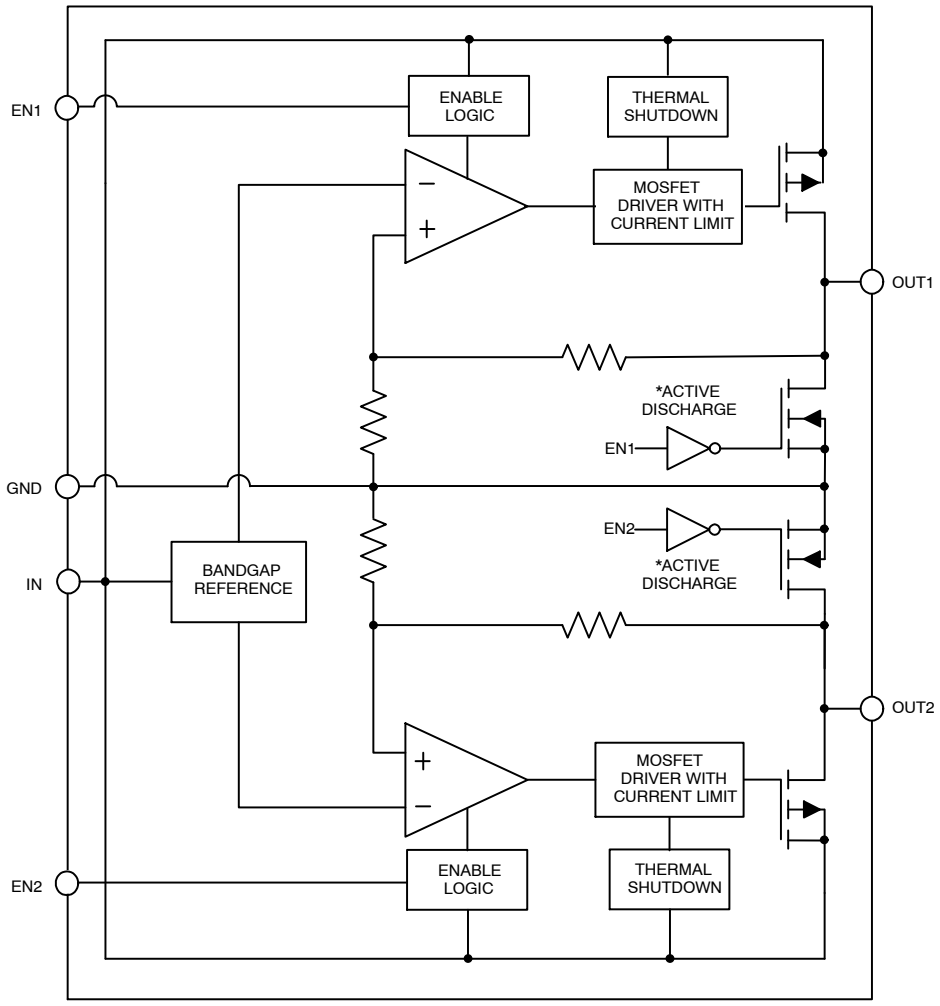


Figure 2. Simplified Schematic Block Diagram

PIN FUNCTION DESCRIPTION

Pin No. XDFN6	Pin Name	Description
1	OUT1	Regulated output voltage of the first channel. A small 0.22 μF ceramic capacitor is needed from this pin to ground to assure stability.
2	OUT2	Regulated output voltage of the second channel. A small 0.22 μF ceramic capacitor is needed from this pin to ground to assure stability.
3	GND	Power supply ground. Soldered to the copper plane allows for effective heat dissipation.
4	EN2	Driving EN2 over 0.9 V turns−on OUT2. Driving EN below 0.4 V turns−off the OUT2 and activates the active discharge.
5	IN	Input pin common for both channels. It is recommended to connect 0.22 μF ceramic capacitor close to the device pin.
6	EN1	Driving EN1 over 0.9 V turns−on OUT1. Driving EN below 0.4 V turns−off the OUT1 and activates the active discharge.
−	EP	Exposed pad must be tied to ground. Soldered to the copper plane allows for effective thermal dissipation.

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V_{IN}	−0.3 V to 6 V	V
Output Voltage	V_{OUT1}, V_{OUT2}	−0.3 V to VIN + 0.3 V or 6 V	V
Enable Inputs	V_{EN1}, V_{EN2}	−0.3 V to VIN + 0.3 V or 6 V	V
Output Short Circuit Duration	t_{SC}	Indefinite	s
Maximum Junction Temperature	$T_{J(MAX)}$	150	°C
Storage Temperature	T_{STG}	−55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD_{HBM}	2000	V
ESD Capability, Machine Model (Note 2)	ESD_{MM}	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTIS and APPLICATION INFORMATION for Safe Operating Area.
2. This device series incorporates ESD protection and is tested by the following methods:
   ESD Human Body Model tested per EIA/JESD22−A114
   ESD Machine Model tested per EIA/JESD22−A115
   Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

THERMAL CHARACTERISTICS (Note 3)

Rating	Symbol	Value	Unit
Thermal Characteristics, XDFN6 1.2 x 1.2 mm, Thermal Resistance, Junction−to−Air Thermal Characterization Parameter, Junction−to−Lead (Pin 2)	 θ_{JA} θ_{JL}	170	°C/W

3. Single component mounted on 1 oz, FR4 PCB with 645mm2 Cu area.

ELECTRICAL CHARACTERISTIC

$-40°C \le T_J \le 85°C$; $V_{IN} = V_{OUT(NOM)} + 1$ V or 2.5 V, whichever is greater; V_{EN} = 0.9 V, I_{OUT} = 1 mA, $C_{IN} = C_{OUT}$ = 0.22 μF. Typical values are at T_J = +25°C. Min/Max values are specified for T_J = −40°C and T_J = 85°C respectively. (Note 4)

Parameter	Test Conditions		Symbol	Min	Typ	Max	Unit
Operating Input Voltage			V_{IN}	1.9		5.25	V
Output Voltage Accuracy	$-40°C \le T_J \le 85°C$	$V_{OUT} > 2$ V	V_{OUT}	−2		+2	%
		$V_{OUT} \le 2$ V		−60		+60	mV
Line Regulation	V_{OUT} + 0.5 V or 2.5 V ≤ V_{IN} ≤ 5 V		Reg_{LINE}		0.02	0.1	%/V
Load Regulation	I_{OUT} = 1 mA to 150 mA		Reg_{LOAD}		15	50	mV
Dropout Voltage (Note 5)	I_{out} = 150 mA	$V_{OUT(nom)}$ = 1.5 V	V_{DO}		370	500	mV
		$V_{OUT(nom)}$ = 1.8 V			270	400	
		$V_{OUT(nom)}$ = 2.6 V			175	260	
		$V_{OUT(nom)}$ = 2.8 V			160	260	
		$V_{OUT(nom)}$ = 3.0 V			150	220	
		$V_{OUT(nom)}$ = 3.3 V			140	220	
Output Current Limit	V_{OUT} = 90% $V_{OUT(nom)}$		I_{CL}	150			mA
Quiescent Current	I_{OUT} = 0 mA, EN1 = V_{IN}, EN2 = 0 V or EN2 = V_{IN}, EN1 = 0 V		I_Q		50	100	μA
	$I_{OUT1} = I_{OUT2}$ = 0 mA, $V_{EN1} = V_{EN2} = V_{IN}$		I_Q		85	200	μA
Shutdown current (Note 6)	$V_{EN} \le 0.4$ V, V_{IN} = 5.25 V		I_{DIS}		0.1	1	μA
EN Pin Threshold Voltage High Threshold Low Threshold	 V_{EN} Voltage increasing V_{EN} Voltage decreasing		 V_{EN_HI} V_{EN_LO}	 0.9		 0.4	V
EN Pin Input Current	$V_{EN} = V_{IN}$ = 5.25 V		I_{EN}		0.3	1.0	μA
Power Supply Rejection Ratio	$V_{IN} = V_{OUT}$+1 V for $V_{OUT} > 2$ V, V_{IN} = 2.5 V, for $V_{OUT} \le 2$ V, I_{OUT} = 10 mA	f = 1 kHz	PSRR		75		dB
Output Noise Voltage	f = 10 Hz to 100 kHz		V_N		75		μV_{rms}
Active Discharge Resistance	V_{IN} = 4 V, V_{EN} < 0.4 V		R_{DIS}		50		Ω
Thermal Shutdown Temperature	Temperature increasing from T_J = +25°C		T_{SD}		160		°C
Thermal Shutdown Hysteresis	Temperature falling from T_{SD}		T_{SDH}	–	20	–	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at $T_J = T_A$ = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
5. Characterized when V_{OUT} falls 100 mV below the regulated voltage at $V_{IN} = V_{OUT(NOM)}$ + 1 V.
6. Shutdown Current is the current flowing into the IN pin when the device is in the disable state.

TYPICAL CHARACTERISTICS

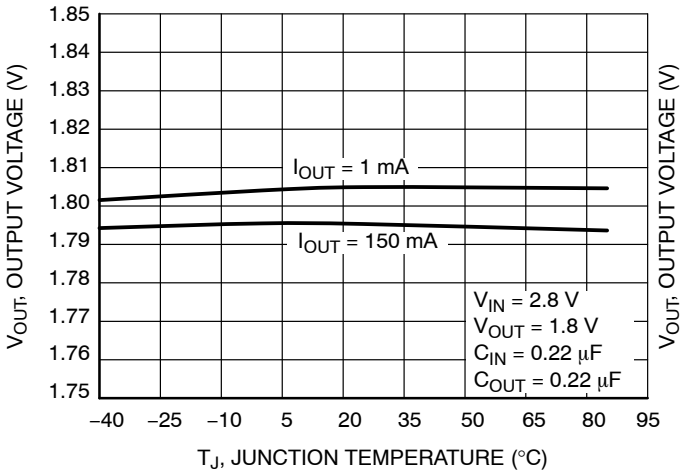


Figure 3. Output Voltage vs. Temperature V_{OUT} = 1.8 V

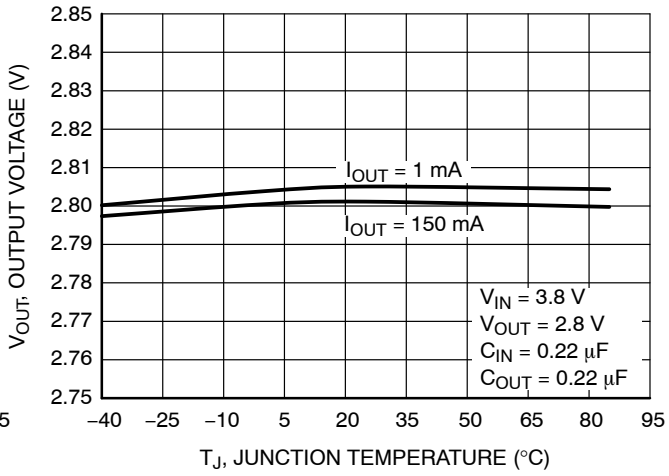


Figure 4. Output Voltage vs. Temperature V_{OUT} = 2.8 V

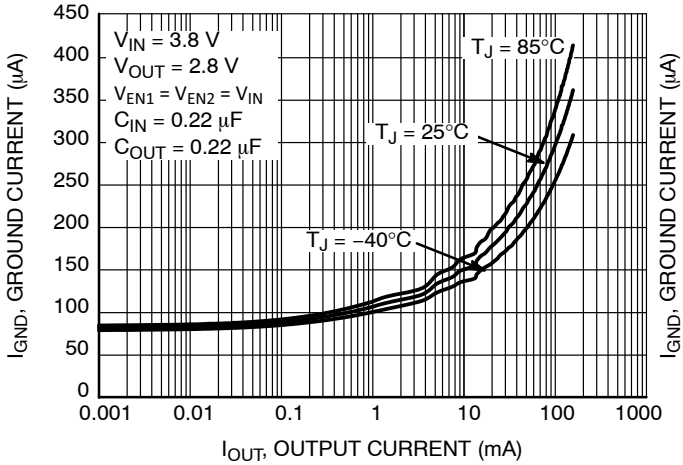


Figure 5. Ground Current vs. Output Current – One Channel Load

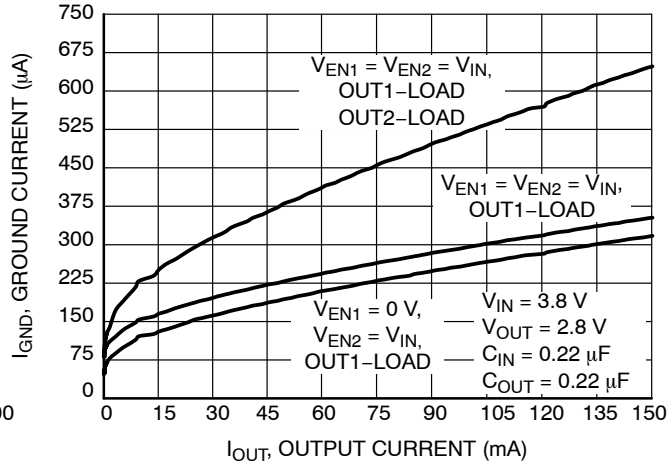


Figure 6. Ground Current vs. Output Current – Different Load Combinations

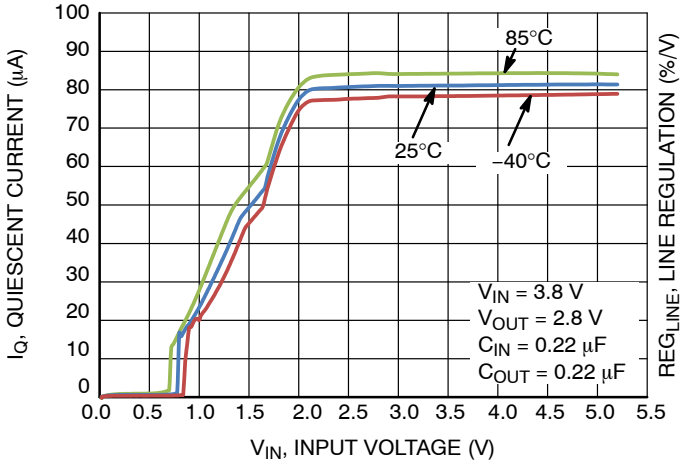


Figure 7. Quiescent Current vs. Input Voltage– Both Outputs ON

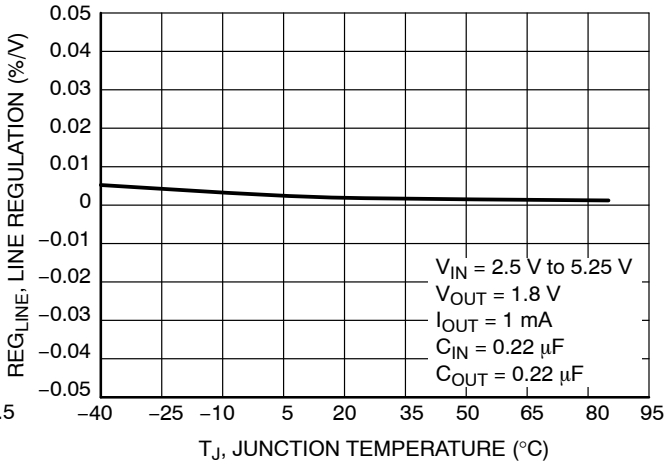


Figure 8. Line Regulation vs. Temperature V_{OUT} = 1.8 V

TYPICAL CHARACTERISTICS

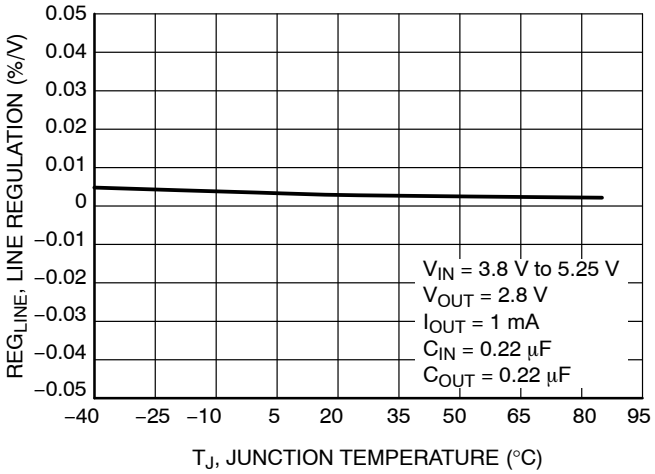


Figure 9. Line Regulation vs. Temperature
V_{OUT} = 2.8 V

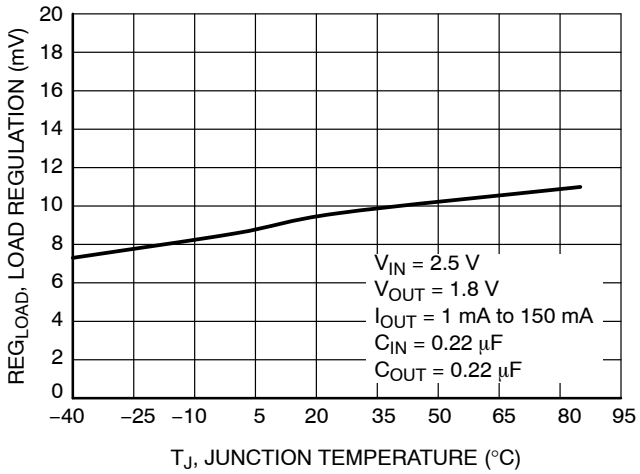


Figure 10. Load Regulation vs. Temperature
V_{OUT} = 1.8 V

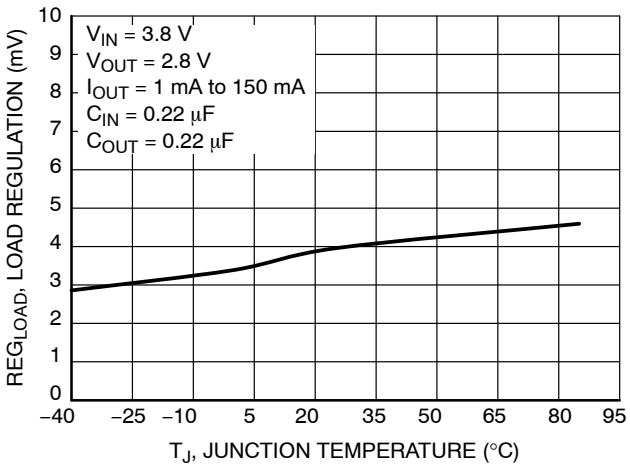


Figure 11. Load Regulation vs. Temperature
V_{OUT} = 2.8 V

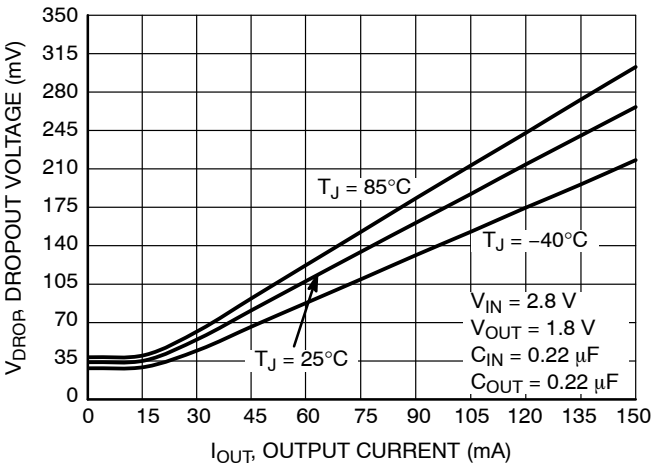


Figure 12. Dropout Voltage vs. Output Current
V_{OUT} = 1.8 V

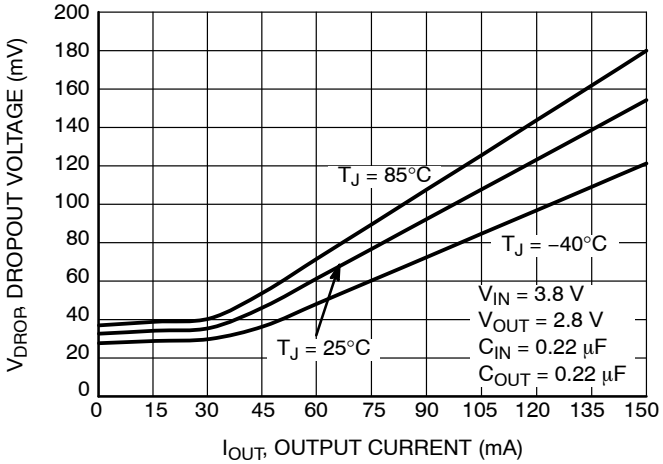


Figure 13. Dropout Voltage vs. Output Current
V_{OUT} = 2.8 V

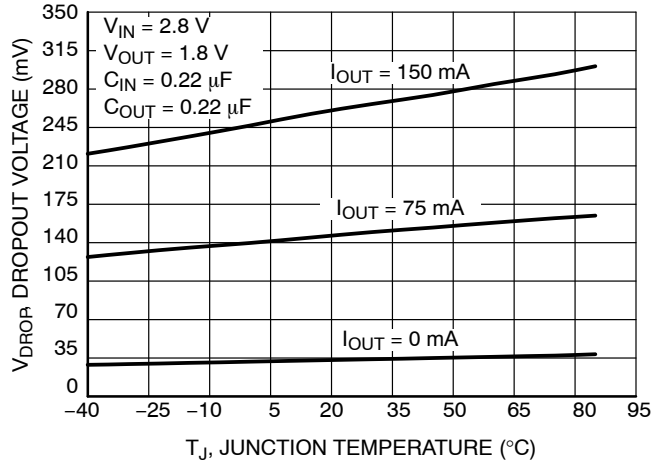


Figure 14. Dropout Voltage vs. Temperature
V_{OUT} = 1.8 V

TYPICAL CHARACTERISTICS

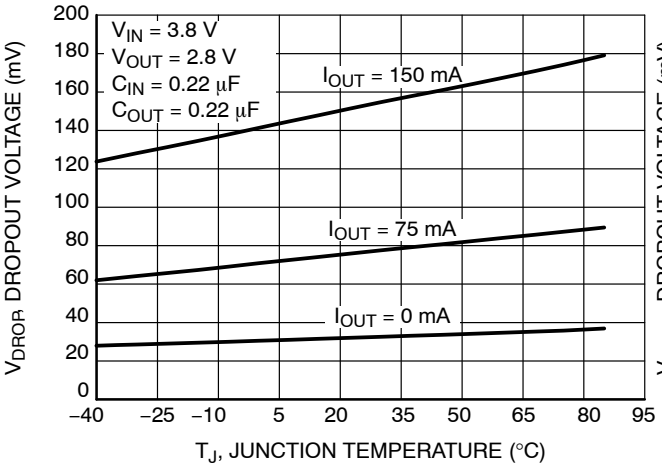


Figure 15. Dropout Voltage vs. Temperature
V_{OUT} = 2.8 V

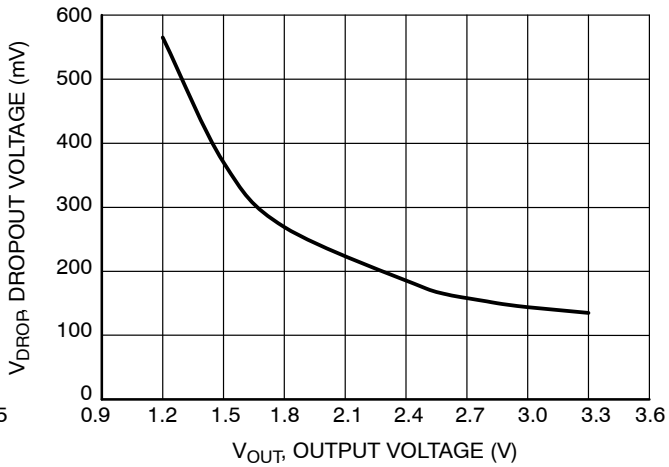


Figure 16. Dropout Voltage vs. Output Voltage

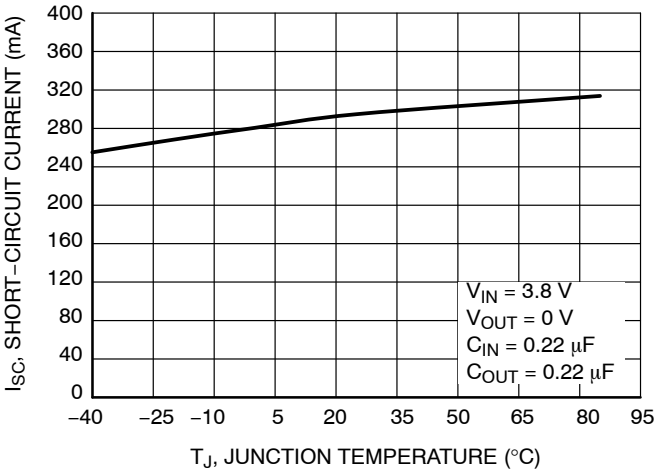


Figure 17. Short−Circuit Current vs. Temperature

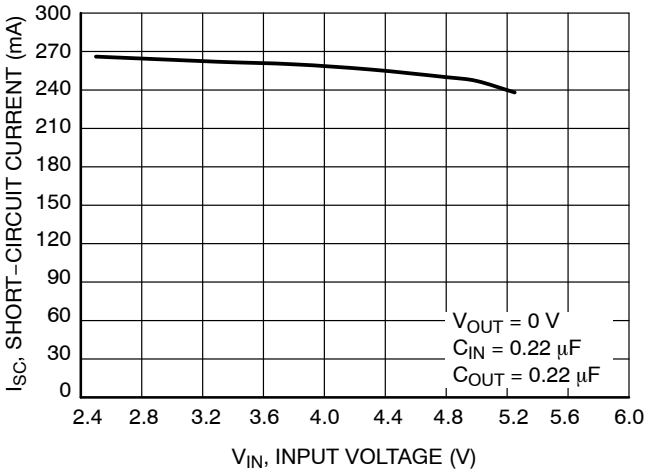


Figure 18. Short−Circuit Current vs. Input Voltage

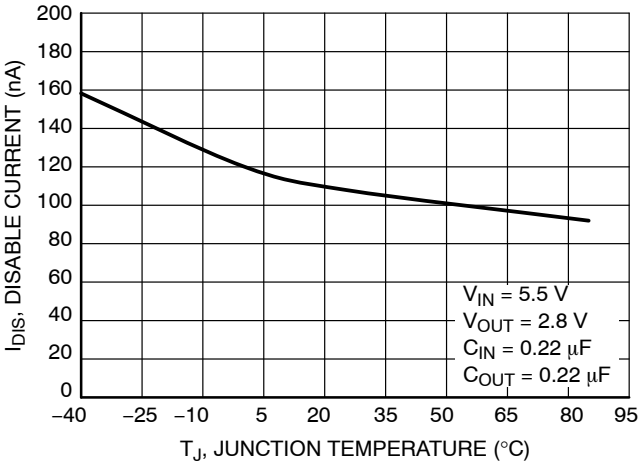


Figure 19. Disable Current vs. Temperature

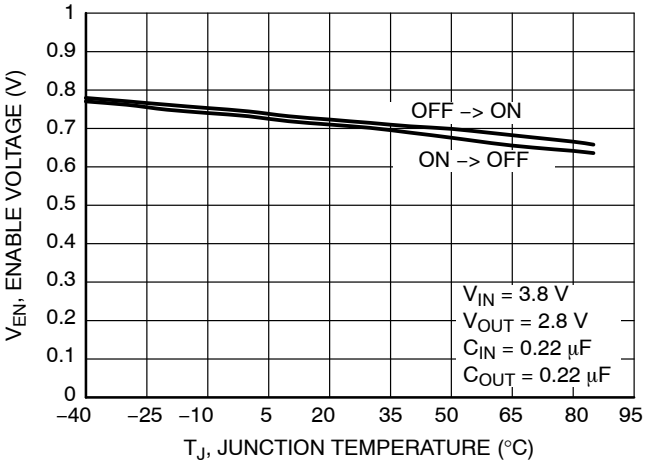


Figure 20. Enable Voltage Threshold vs. Temperature

TYPICAL CHARACTERISTICS

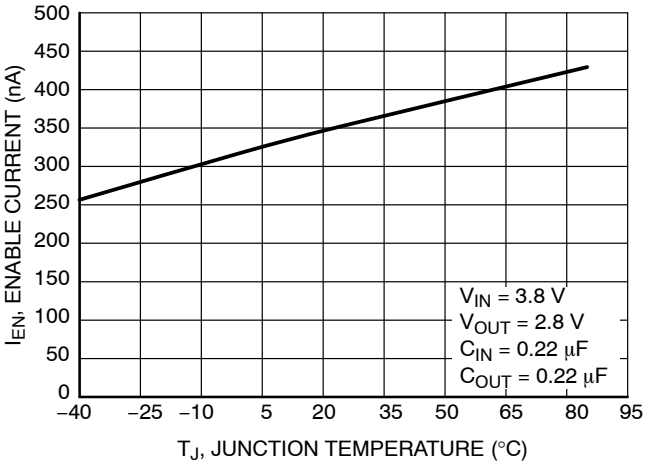


Figure 21. Current to Enable Pin vs. Temperature

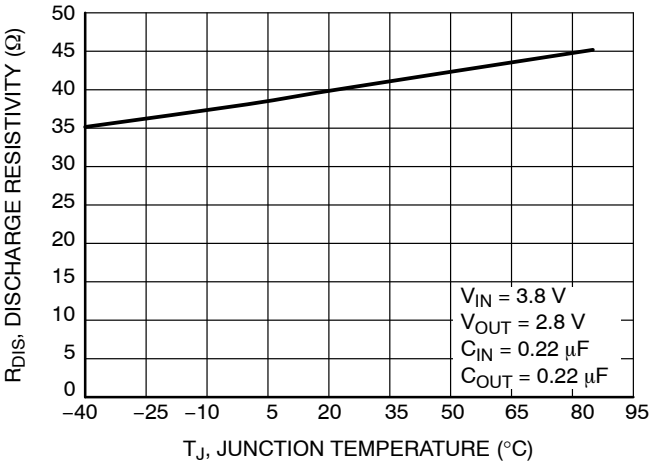


Figure 22. Discharge Resistance vs. Temperature

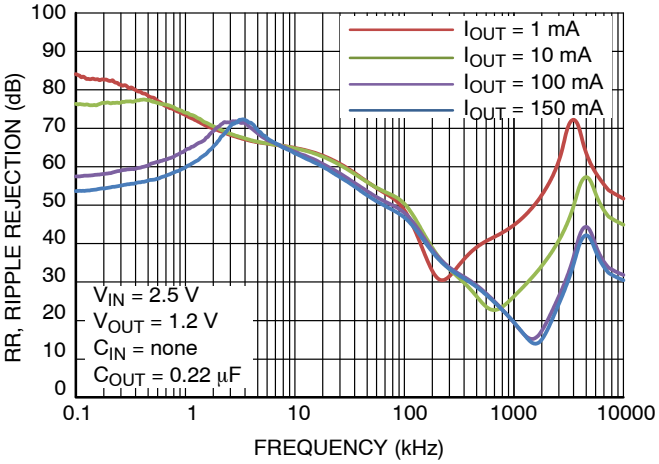


Figure 23. Power Supply Rejection Ratio, V_{OUT} = 1.2 V, C_{OUT} = 0.22 μF

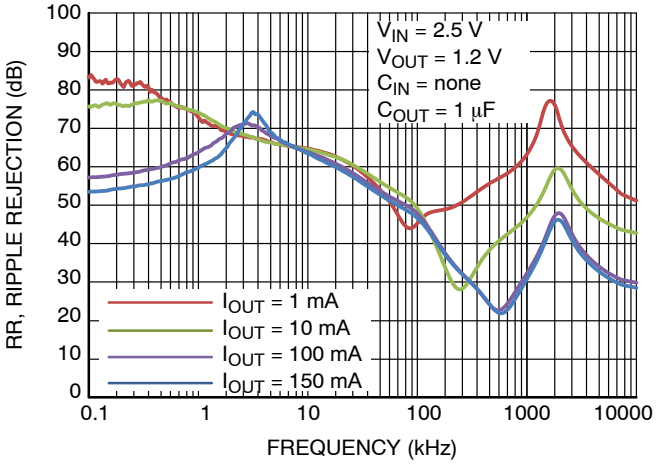


Figure 24. Power Supply Rejection Ratio, V_{OUT} = 1.2 V, C_{OUT} = 1 μF

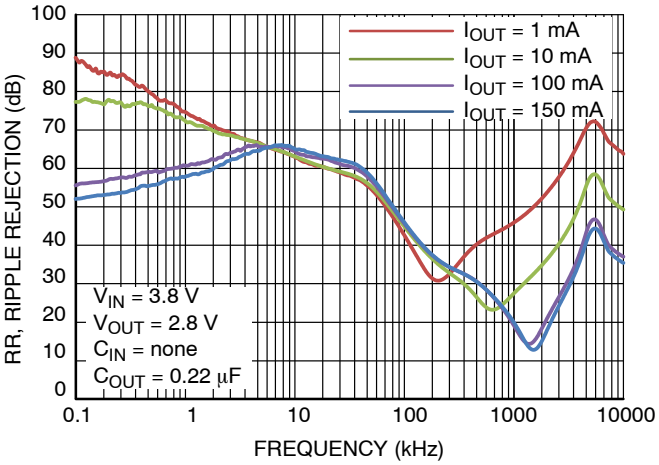


Figure 25. Power Supply Rejection Ratio, V_{OUT} = 2.8 V, C_{OUT} = 0.22 μF

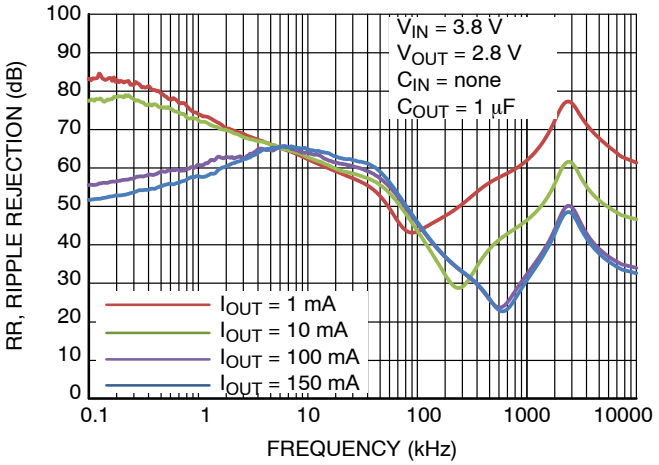
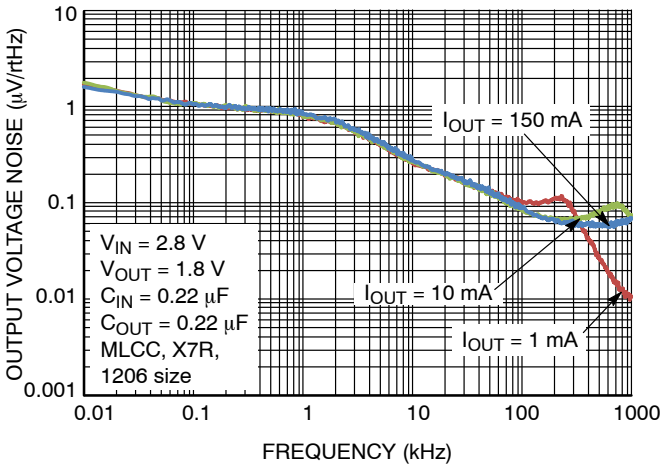
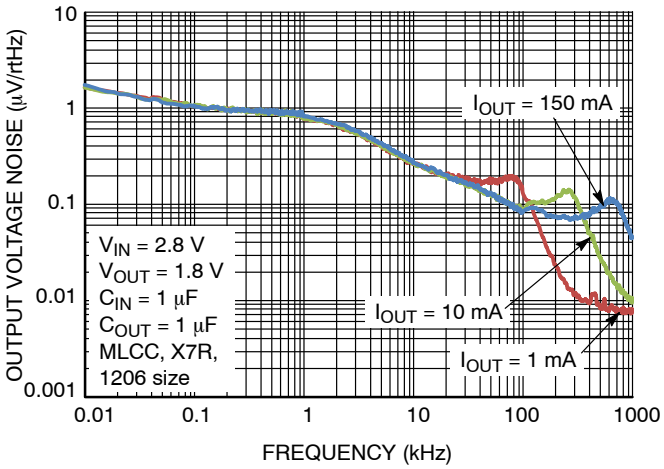


Figure 26. Power Supply Rejection Ratio, V_{OUT} = 2.8 V, C_{OUT} = 1 μF



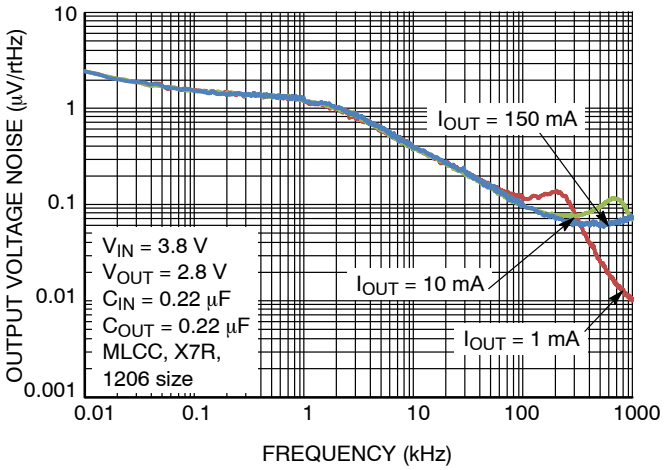
I_{OUT}	RMS Output Noise (μV)	
	10 Hz – 100 kHz	100 Hz – 100 kHz
1 mA	68.07	67.07
10 mA	67.30	66.31
150 mA	69.74	68.80

Figure 27. Output Voltage Noise Spectral Density for V_{OUT} = 1.8 V, C_{OUT} = 220 nF



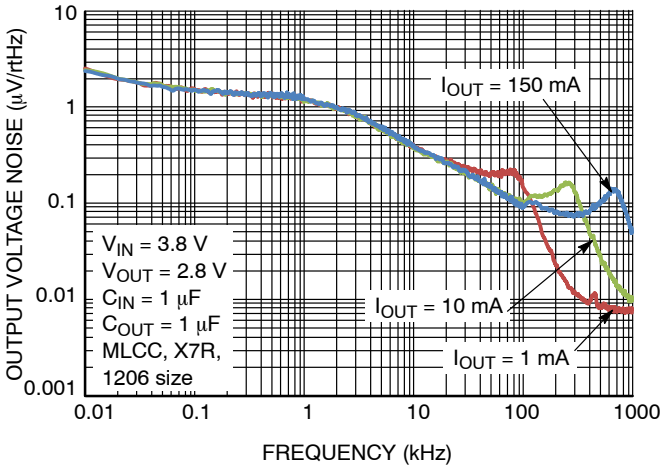
I_{OUT}	RMS Output Noise (μV)	
	10 Hz – 100 kHz	100 Hz – 100 kHz
1 mA	76.23	75.33
10 mA	67.12	66.12
150 mA	69.06	68.12

Figure 28. Output Voltage Noise Spectral Density for V_{OUT} = 1.8 V, C_{OUT} = 1 μF



I_{OUT}	RMS Output Noise (μV)	
	10 Hz – 100 kHz	100 Hz – 100 kHz
1 mA	93.42	91.99
10 mA	92.88	91.45
150 mA	94.67	93.26

Figure 29. Output Voltage Noise Spectral Density for V_{OUT} = 2.8 V, C_{OUT} = 220 nF



I_{OUT}	RMS Output Noise (μV)	
	10 Hz – 100 kHz	100 Hz – 100 kHz
1 mA	102.14	100.86
10 mA	93.03	91.59
150 mA	94.74	93.12

Figure 30. Output Voltage Noise Spectral Density for V_{OUT} = 2.8 V, C_{OUT} = 1 μF

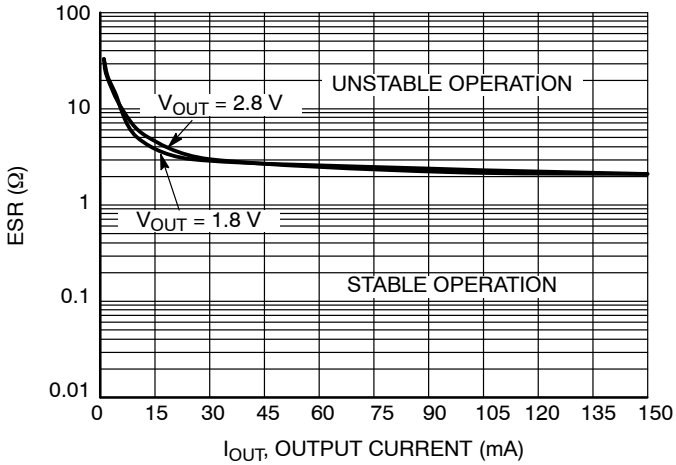


Figure 31. Output Capacitor ESR vs. Output Current

TYPICAL CHARACTERISTICS

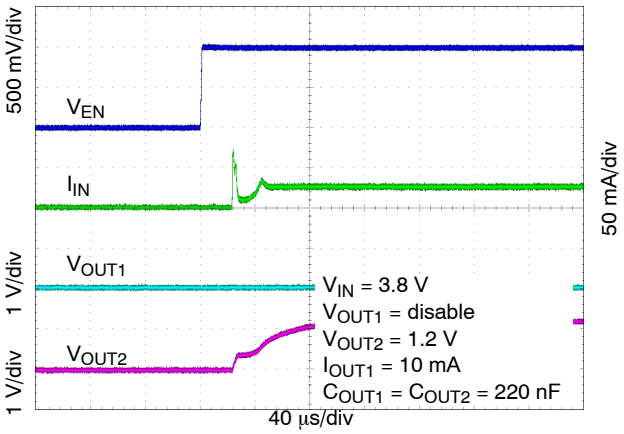


Figure 32. Enable Turn−on Response − VR1 = Off, VR2 = 10 mA

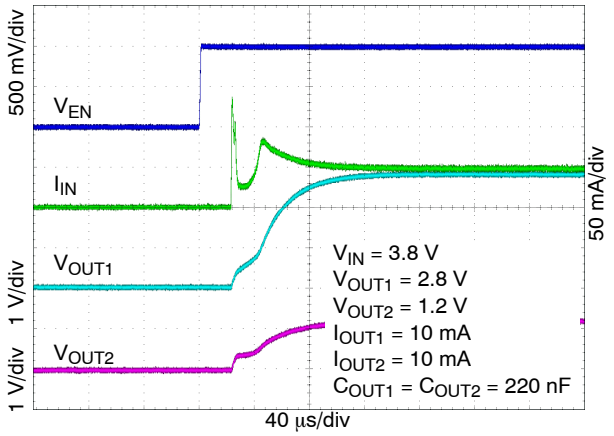


Figure 33. Enable Turn−on Response − VR1 = 10 mA, VR2 = 10 mA

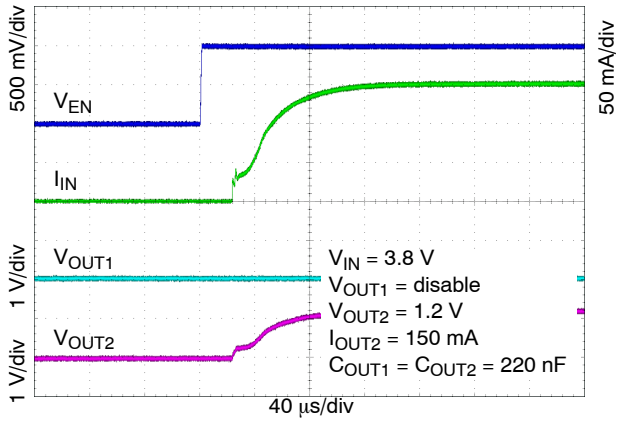


Figure 34. Enable Turn−on Response − VR1 = Off, VR2 = 150 mA

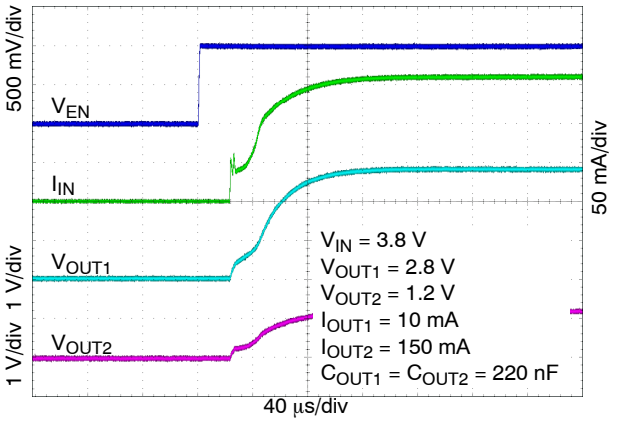


Figure 35. Enable Turn−on Response − VR1 = 10 mA, VR2 = 150 mA

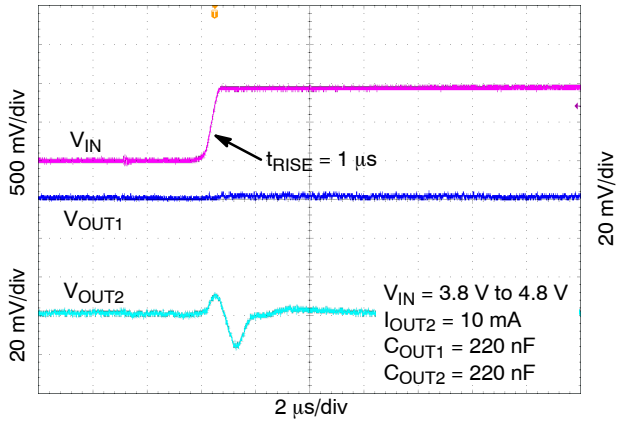


Figure 36. Line Transient Response − Rising Edge, V_{EN1} = 0 V, V_{EN2} = V_{IN}, V_{OUT2} = 3.3 V, I_{OUT2} = 10 mA

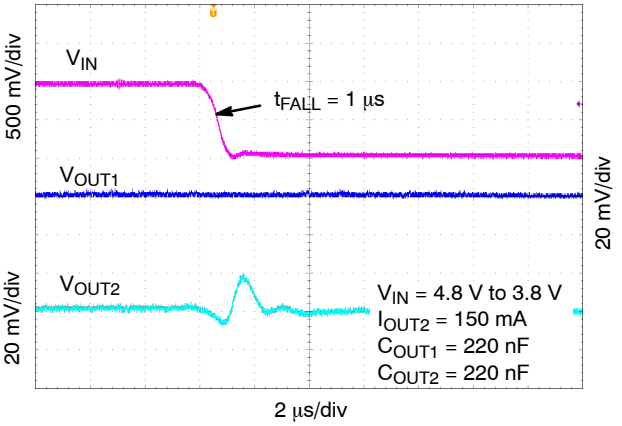


Figure 37. Line Transient Response − Falling Edge, V_{EN1} = 0 V, V_{EN2} = V_{IN}, V_{OUT2} = 3.3 V, I_{OUT2} = 10 mA

TYPICAL CHARACTERISTICS

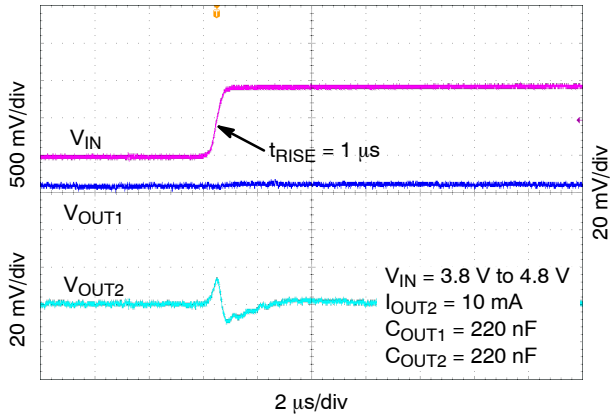


Figure 38. Line Transient Response – Rising Edge, V_{EN1} = 0 V, V_{EN2} = V_{IN}, V_{OUT2} = 3.3 V, I_{OUT2} = 150 mA

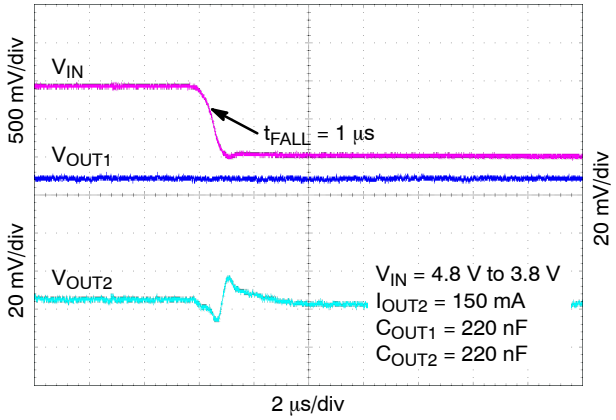


Figure 39. Line Transient Response – Falling Edge, V_{EN1} = 0 V, V_{EN2} = V_{IN}, V_{OUT2} = 3.3 V, I_{OUT2} = 150 mA

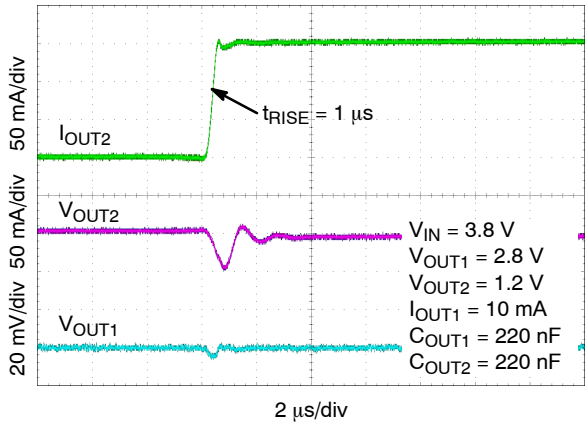


Figure 40. Load Transient Response – Rising Edge, I_{OUT} = 1 mA to 150 mA

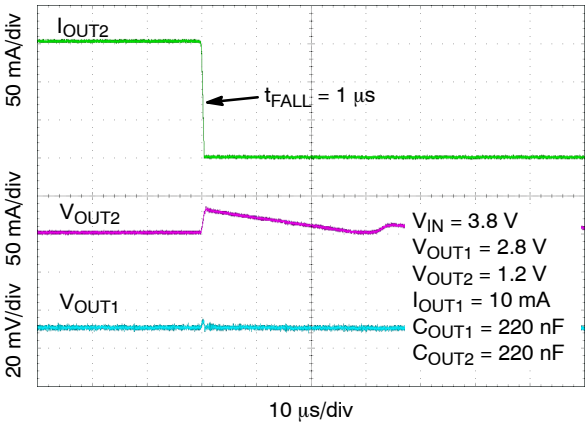


Figure 41. Load Transient Response – Falling Edge, I_{OUT} = 150 mA to 1 mA

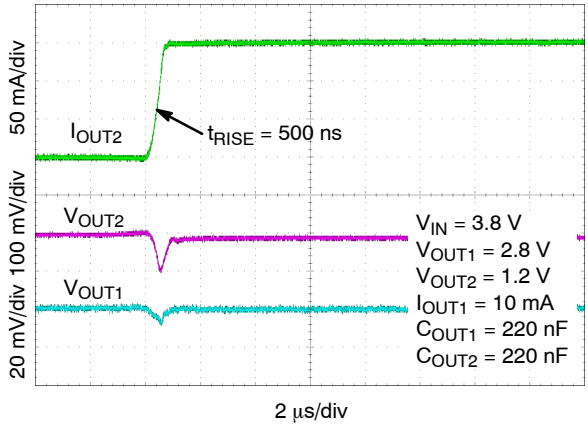


Figure 42. Load Transient Response – Rising Edge, I_{OUT} = 0.1 mA to 150 mA

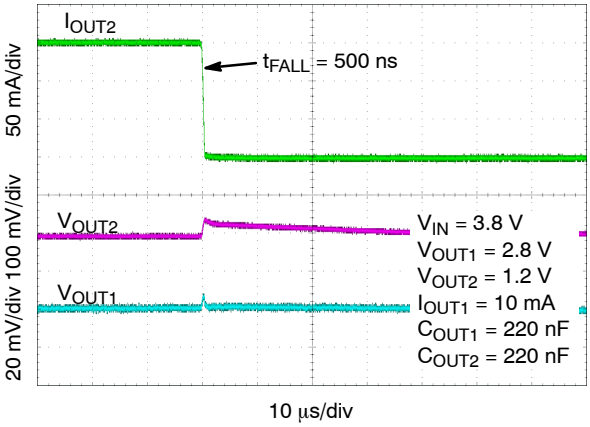


Figure 43. Load Transient Response – Falling Edge, I_{OUT} = 150 mA to 0.1 mA

TYPICAL CHARACTERISTICS

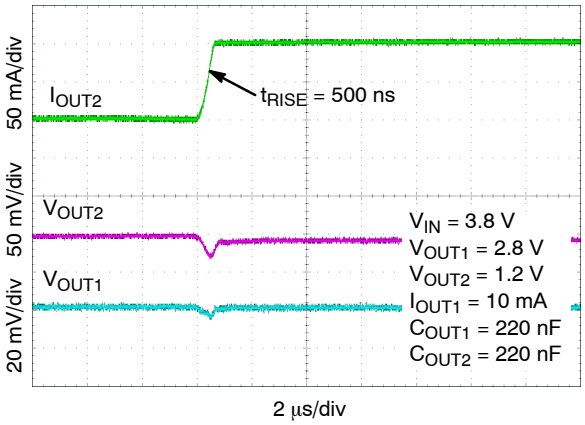


Figure 44. Load Transient Response – Rising Edge, I_{OUT} = 50 mA to 150 mA

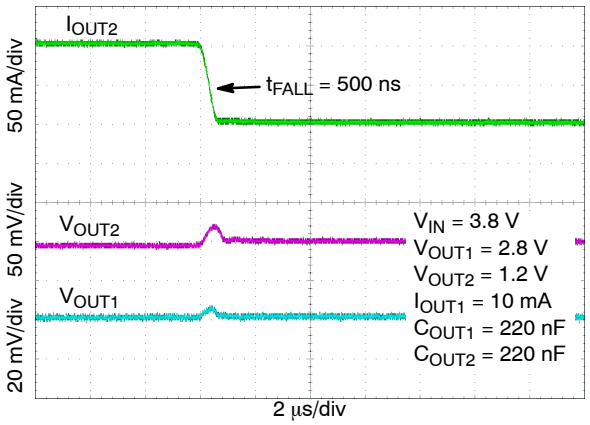


Figure 45. Load Transient Response – Falling Edge, I_{OUT} = 150 mA to 50 mA

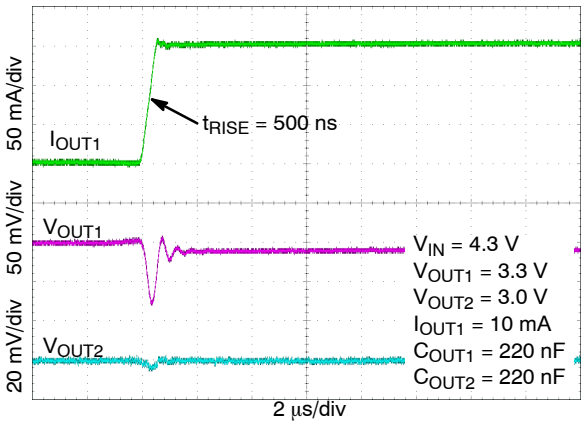


Figure 47. Load Transient Response – Rising Edge, I_{OUT} = 1 mA to 150 mA

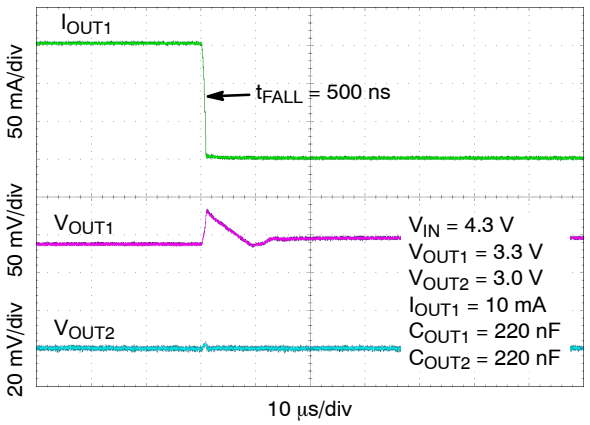


Figure 48. Load Transient Response – Falling Edge, I_{OUT} = 150 mA to 1 mA

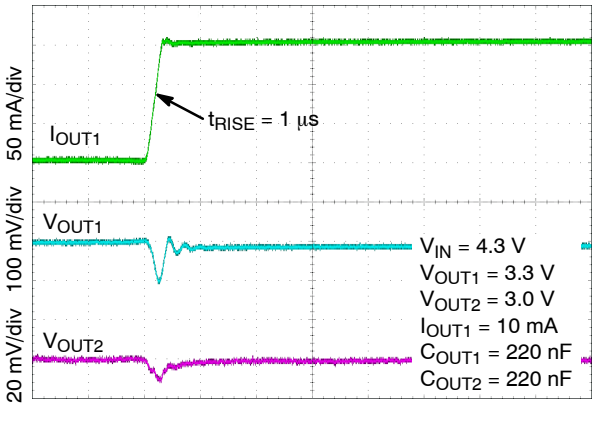


Figure 46. Load Transient Response – Rising Edge, I_{OUT} = 0.1 mA to 150 mA

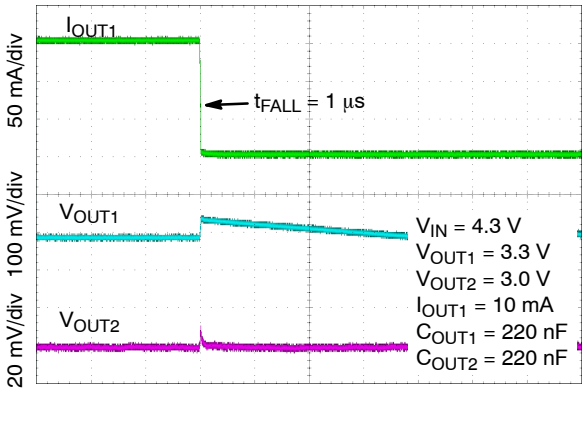


Figure 49. Load Transient Response – Falling Edge, I_{OUT} = 150 mA to 0.1 mA

TYPICAL CHARACTERISTICS

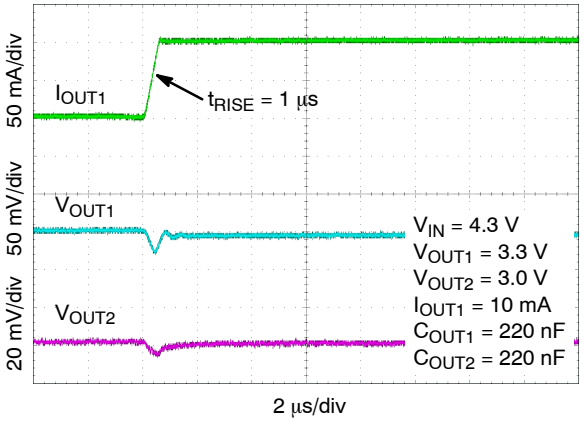


Figure 50. Load Transient Response – Rising Edge, I_{OUT} = 50 mA to 150 mA

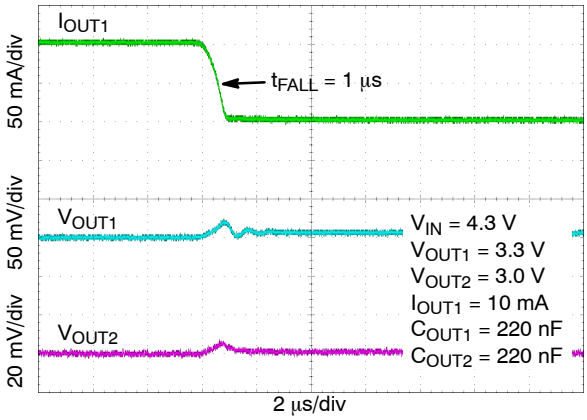


Figure 51. Load Transient Response – Falling Edge, I_{OUT} = 150 mA to 50 mA

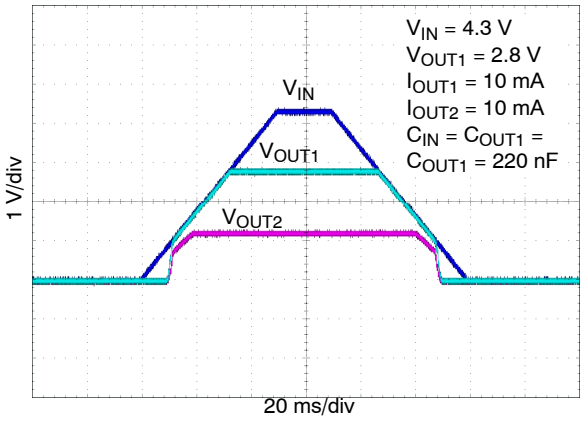


Figure 52. Turn−on/off – Slow Rising V_{IN}

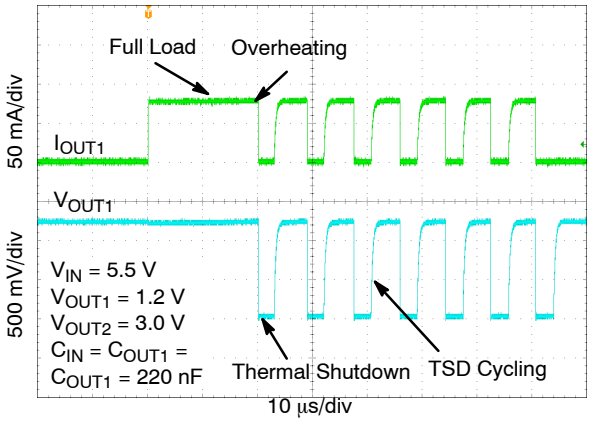


Figure 53. Short−Circuit and Thermal Shutdown

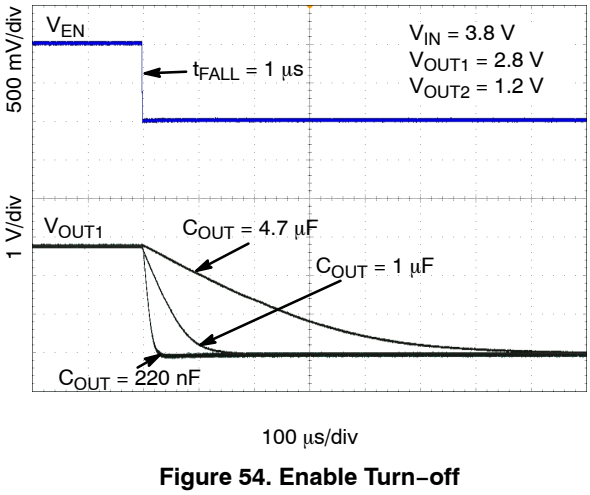


Figure 54. Enable Turn−off

APPLICATIONS INFORMATION

General

The NCP152 is a dual output high performance 150 mA Low Dropout Linear Regulator. This device delivers very high PSRR (75 dB at 1 kHz) and excellent dynamic performance as load/line transients. In connection with low quiescent current this device is very suitable for various battery powered applications such as tablets, cellular phones, wireless and many others. Each output is fully protected in case of output overload, output short circuit condition and overheating, assuring a very robust design. The NCP152 device is housed in XDFN−6 1.2 mm x 1.2 mm package which is useful for space constrains application.

Input Capacitor Selection (C_{IN})

It is recommended to connect at least a 0.22 μF Ceramic X5R or X7R capacitor as close as possible to the IN pin of the device. This capacitor will provide a low impedance path for unwanted AC signals or noise modulated onto constant input voltage. There is no requirement for the min. or max. ESR of the input capacitor but it is recommended to use ceramic capacitors for their low ESR and ESL. A good input capacitor will limit the influence of input trace inductance and source resistance during sudden load current changes. Larger input capacitor may be necessary if fast and large load transients are encountered in the application.

Output Decoupling (C_{OUT})

The NCP152 requires an output capacitor for each output connected as close as possible to the output pin of the regulator. The recommended capacitor value is 0.22 μF and X7R or X5R dielectric due to its low capacitance variations over the specified temperature range. The NCP152 is designed to remain stable with minimum effective capacitance of 0.15 μF to account for changes with temperature, DC bias and package size. Especially for small package size capacitors such as 0201 the effective capacitance drops rapidly with the applied DC bias.

There is no requirement for the minimum value of Equivalent Series Resistance (ESR) for the C_{OUT} but the maximum value of ESR should be less than 2 Ω. Larger output capacitors and lower ESR could improve the load transient response or high frequency PSRR. It is not recommended to use tantalum capacitors on the output due to their large ESR. The equivalent series resistance of tantalum capacitors is also strongly dependent on the temperature, increasing at low temperature.

Enable Operation

The NCP152 uses the dedicated EN pin for each output channel. This feature allows driving outputs separately.

If the EN pin voltage is <0.4 V the device is guaranteed to be disabled. The pass transistor is turned−off so that there is virtually no current flow between the IN and OUT. The active discharge transistor is active so that the output voltage V_{OUT} is pulled to GND through a 50 Ω resistor. In the disable state the device consumes as low as typ. 10 nA from the V_{IN}.

If the EN pin voltage >0.9 V the device is guaranteed to be enabled. The NCP152 regulates the output voltage and the active discharge transistor is turned−off.

The both EN pin has internal pull−down current source with typ. value of 300 nA which assures that the device is turned−off when the EN pin is not connected. In the case where the EN function isn't required the EN should be tied directly to IN.

Output Current Limit

Output Current is internally limited within the IC to a typical 280 mA. The NCP152 will source this amount of current measured with a voltage drops on the 90% of the nominal V_{OUT}. If the Output Voltage is directly shorted to ground (V_{OUT} = 0 V), the short circuit protection will limit the output current to 300 mA (typ). The current limit and short circuit protection will work properly over whole temperature range and also input voltage range. There is no limitation for the short circuit duration. This protection works separately for each channel. Short circuit on the one channel do not influence second channel which will work according to specification.

Thermal Shutdown

When the die temperature exceeds the Thermal Shutdown threshold (T_{SD} − 160°C typical), Thermal Shutdown event is detected and the affected channel is turn−off. Second channel still working. The channel which is overheated will remain in this state until the die temperature decreases below the Thermal Shutdown Reset threshold (T_{SDU} − 140°C typical). Once the device temperature falls below the 140°C the appropriate channel is enabled again. The thermal shutdown feature provides the protection from a catastrophic device failure due to accidental overheating. This protection is not intended to be used as a substitute for proper heat sinking. The long duration of the short circuit condition to some output channel could cause turn−off other output when heat sinking is not enough and temperature of the other output reach T_{SD} temperature.

Power Dissipation

As power dissipated in the NCP152 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part.

The maximum power dissipation the NCP152 can handle is given by:

$$P_{D(MAX)} = \frac{\left[125^{\circ}C - T_A\right]}{\theta_{JA}} \qquad \text{(eq. 1)}$$

The power dissipated by the NCP152 for given application conditions can be calculated from the following equations:

$$P_D \approx V_{IN} \times I_{GND} + I_{OUT1}(V_{IN} - V_{OUT1}) + I_{OUT2}(V_{IN} - V_{OUT2}) \quad \text{(eq. 2)}$$

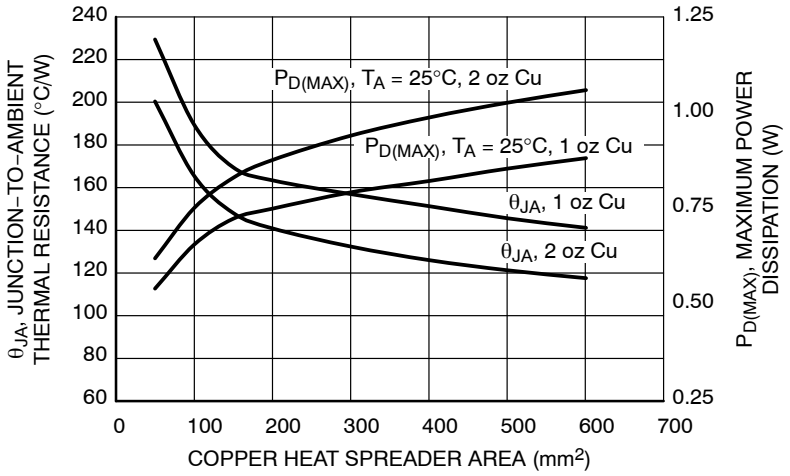


Figure 55. θ_{JA} vs. Copper Area (XDFN−6)

Reverse Current

The PMOS pass transistor has an inherent body diode which will be forward biased in the case that $V_{OUT} > V_{IN}$. Due to this fact in cases, where the extended reverse current condition can be anticipated the device may require additional external protection.

Power Supply Rejection Ratio

The NCP152 features very good Power Supply Rejection ratio. If desired the PSRR at higher frequencies in the range 100 kHz − 10 MHz can be tuned by the selection of C_{OUT} capacitor and proper PCB layout.

Turn−On Time

The turn−on time is defined as the time period from EN assertion to the point in which V_{OUT} will reach 98% of its nominal value. This time is dependent on various application conditions such as $V_{OUT(NOM)}$, C_{OUT}, T_A.

PCB Layout Recommendations

To obtain good transient performance and good regulation characteristics place input and output capacitors close to the device pins and make the PCB traces wide. In order to minimize the solution size, use 0402 capacitors. Larger copper area connected to the pins will also improve the device thermal resistance. The actual power dissipation can be calculated from the equation above (Equation 2). Expose pad should be tied the shortest path to the GND pin.

ORDERING INFORMATION

Device	Voltage Option* (OUT1/OUT2)	Marking	Marking Rotation	Package	Shipping†
NCP152MX150280TCG	1.5 V/2.8 V	D	0°	XDFN-6 (Pb-Free)	3000 / Tape & Reel
NCP152MX180280TCG	1.8 V/2.8 V	A	0°		
NCP152MX180150TCG	1.8 V/1.5 V	Q	0°		
NCP152MX280120TCG (Note 7)	2.8 V/1.2 V	V	0°		3000 or 5000 / Tape & Reel (Note 7)
NCP152MX280180TCG	2.8 V/1.8 V	A	90°		3000 / Tape & Reel
NCP152MX300280TCG	3.0 V/2.8 V	F	0°		
NCP152MX300180TCG	3.0 V/1.8 V	J	0°		
NCP152MX300300TCG	3.0 V/3.0 V	P	0°		
NCP152MX330180TCG	3.3 V/1.8 V	E	0°		
NCP152MX330280TCG	3.3 V/2.8 V	K	0°		
NCP152MX330330TCG	3.3 V/3.3 V	L	0°		
NCP152MX330300TCG	3.3 V/3.0 V	2	0°		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*Contact factory for other voltage options. Output voltage range 1.0 V to 3.3 V with step 50 mV.

7. Product processed after October 1, 2022 are shipped with quantity 5000 units / Tape & Reel.

ZigBee is a registered trademark of ZigBee Alliance.
Bluetooth is a registered trademark of Bluetooth SIG.

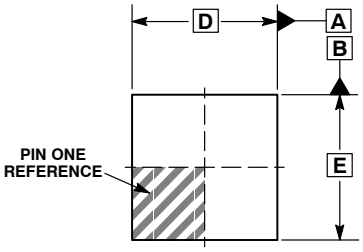
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

ON Semiconductor®

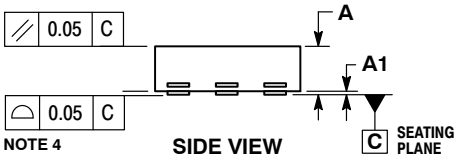
XDFN6 1.20x1.20, 0.40P
CASE 711AT
ISSUE C

SCALE 4:1

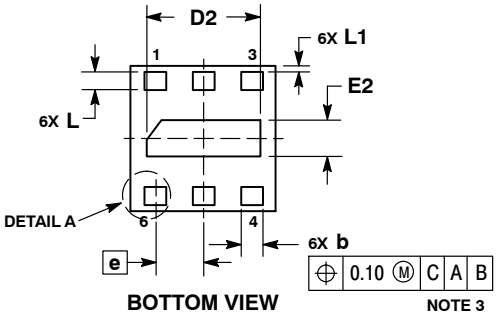
DATE 04 DEC 2015



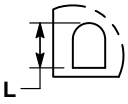
TOP VIEW



SIDE VIEW



BOTTOM VIEW



DETAIL A
OPTIONAL CONSTRUCTION

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO THE PLATED TERMINALS.
4. COPLANARITY APPLIES TO THE PAD AS WELL AS THE TERMINALS.

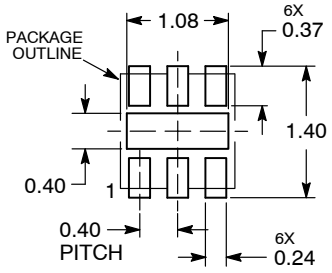
	MILLIMETERS		
DIM	MIN	TYP	MAX
A	0.30	0.37	0.45
A1	0.00	0.03	0.05
b	0.13	0.18	0.23
D	1.15	1.20	1.25
D2	0.84	0.94	1.04
E	1.15	1.20	1.25
E2	0.20	0.30	0.40
e	0.40 BSC		
L	0.15	0.20	0.25
L1	0.00	0.05	0.10

GENERIC MARKING DIAGRAM*

XX = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present.

RECOMMENDED MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	**98AON76141F**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.
DESCRIPTION:	**XDFN6, 1.20 X 1.20, 0.40P**	**PAGE 1 OF 1**

ON Semiconductor and ON are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

onsemi, , and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent−Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as−is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:
Technical Library: www.onsemi.com/design/resources/technical−documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support
For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- View NCP152MX300280TCG on WIN SOURCE
- ON Semiconductor Information

Optimize Your Supply Chain with WIN SOURCE Solutions

- Global Sourcing Solution
- Obsolete Management
- Cost Control Management
- Shortage Management
- Alternative Solution
- Excess Inventory Management